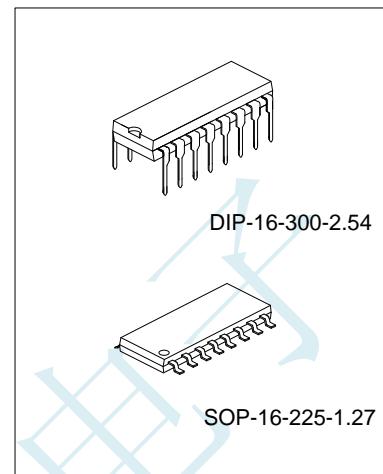


HIGH VOLTAGE AND HIGH CURRENT DARLINGTON TRANSISTOR ARRAY

DESCRIPTION

The ULN2003 is a monolithic high voltage and high current Darlington transistor arrays. It consists of seven NPN darlington pairs that features high-voltage outputs with common-cathode clamp diode for switching inductive loads. The collector-current rating of a single darlington pair is 500mA. The darlington pairs may be paralleled for higher current capability. Applications include relay drivers, hammer drivers, lampdrivers, display drivers(LED gas discharge), line drivers, and logic buffers.

The ULN2003 has a 2.7k Ω series base resistor for each darlington pair for operation directly with TTL or 5V CMOS devices.



FEATURES

- * 500mA rated collector current(Single output)
- * High-voltage outputs: 50V
- * Inputs compatible with various types of logic.
- * Relay driver application

ORDERING INFORMATION

Ordering Number	Package	Print Number	Free	Packing
ULN2003-DIA-R-T	DIP-16-300-2.54	ULN2003	RoHS	Tube
ULN2003-SOA-R-T	SOP-16-225-1.27	ULN2003	RoHS	Tube
ULN2003-SOA-R-R	SOP-16-225-1.27	ULN2003	RoHS	Tape Reel

ULN2003 - DIA - R - T

Packing Type: T:Tube, R:Tape Reel, K: Bulk,
B: Tape Box

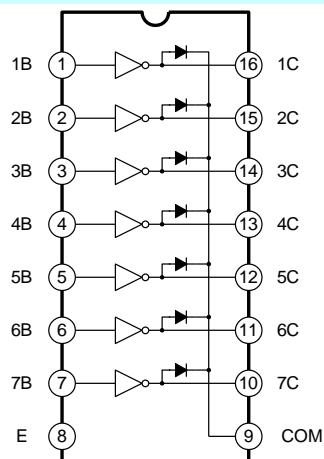
Green Package: R:RoHS

Package: DIA:DIP-16-300-2.54;

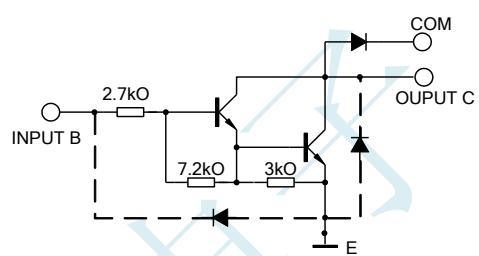
SOA:SOP-16-225-1.27

Number

LOGIC DIAGRAM



SCHEMATIC(EACH DARLINGTON PAIR)

ABSOLUTE MAXIMUM RATINGS($T_a=25^{\circ}\text{C}$)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CE}	50	V
Input Voltage	V _I	30	V
Peak Collector Current	I _o	500	mA
Total Emitter-terminal	I _{OK}	500	mA
Power Dissipation	P _d	(DIP-16)1.47 (SOP-16)1.25(Note2)	W
Operating Temperature	T _{opr}	-20~ +85	°C
Storage Temperature	T _{stg}	-65 ~ +150	°C

Note: 1. All voltage values are with respect to the emitter/substrate terminal E, unless otherwise noted.

2. On PCB

ELECTRICAL CHARACTERISTICS (Ta=25°C,unless otherwise specified)

Characteristic	Test Figure	Symbol	Test Conditions	Min	Typ	Max	Units
On-state Input Voltage	6	VI(ON)	VCE=2V,Ic=200mA			2.4	V
			VCE=2V,Ic=250mA			2.7	
			VCE=2V,Ic=300mA			3	
Collector-Emitter Saturation Voltage	5	VCE(SAT)	Ii=250μA,Ic=100mA		0.9	1.1	V
			Ii=350μA,Ic=200mA		1	1.3	
			Ii=500μA,Ic=350mA		1.2	1.6	
Collector Cutoff Current	1	ICEX	VCE=50V,Ii=0			50	μA
	2		VCE=50V,Ii=0,Ta=70°C			100	
Clamp Forward Voltage	8	VF	IF=350mA		1.7	2	V
Off-state Input Current	3	II(OFF)	IC=500μA, Ta=70°C	50	65		μA
Input Current	4	II	VI=3.85V		0.95	1.35	mA
Clamp Reverse Current	7	IR	VR=50V			50	μA
			VR=50V, Ta=70°C			100	
Input Capacitance	--	CI	VI=0,f=1MHz		15	25	pF
Propagation delay time, low-to-high-level output	9	tPLH			0.25	1	μs
Propagation delay time, high-to-low-level output	9	tPHL			0.25	1	μs
High-level output Voltage after switching	10	VOH	Vs=50V,Io=300mA	Vs-20			mV

TEST CIRCUITS

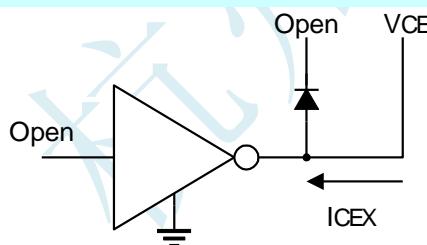


Figure 1 ICEX Test Circuit

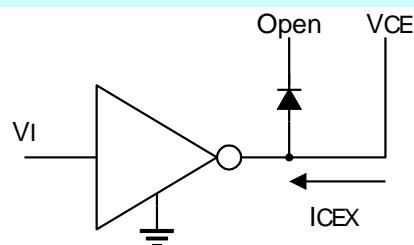


Figure 2 ICEX Test Circuit

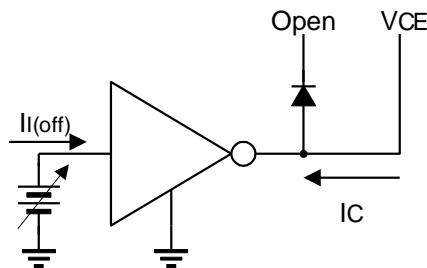


Figure 3 II(off) Test Circuit

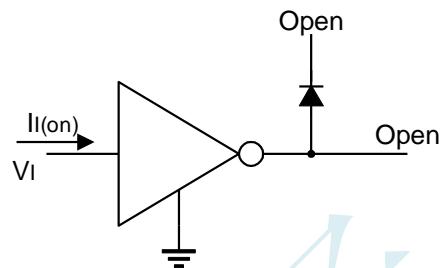
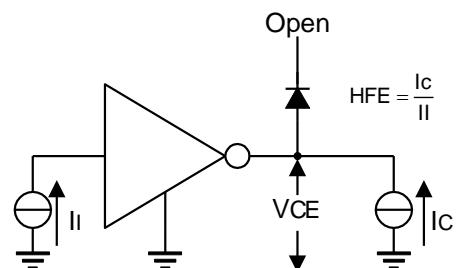


Figure 4 II(on) Test Circuit



Note: I_L is fixed for measuring $V_{CE}(\text{sat})$, variable for measuring HFE.

Figure 5 HFE, VCE(sat) Test Circuit

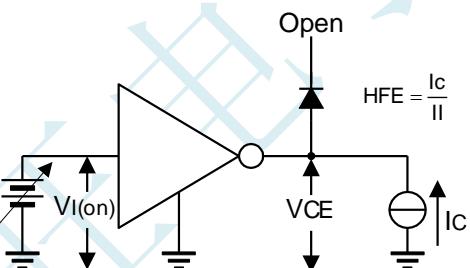


Figure 6 VI(on) Test Circuit

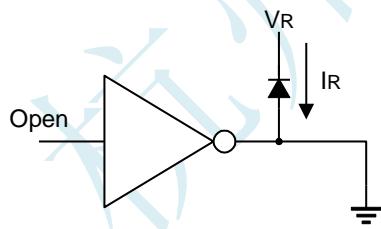


Figure 7 IR Test Circuit

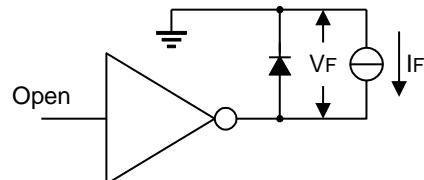


Figure 8 VF Test Circuit



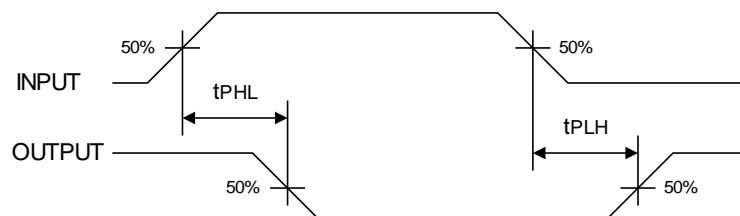
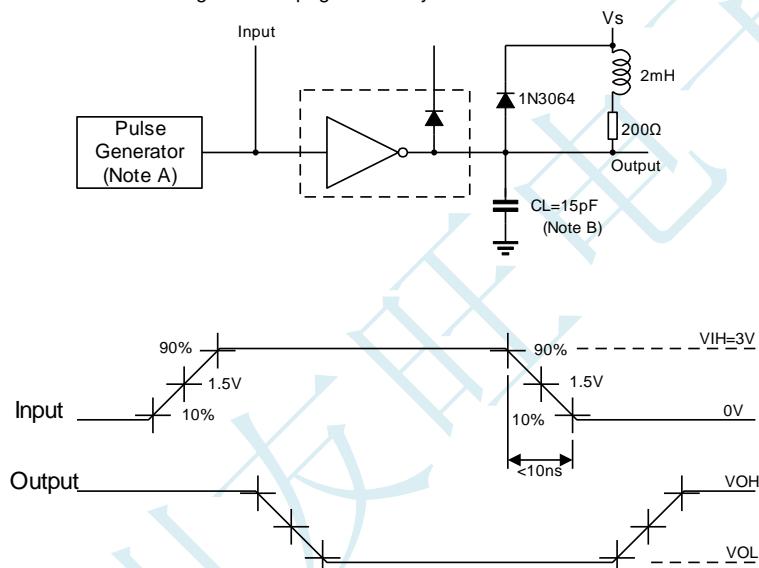


Figure 9. Propagation Delay Time Waveforms



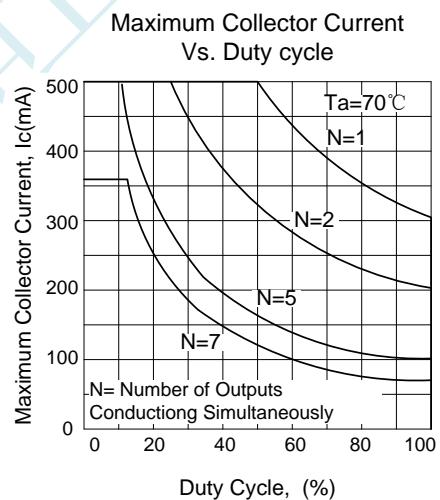
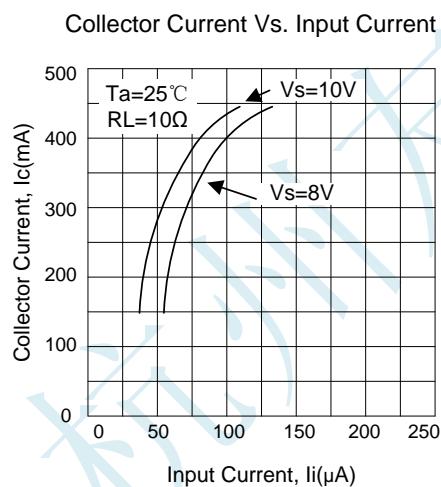
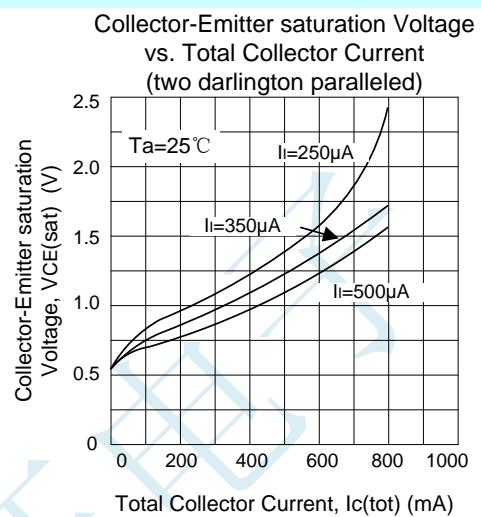
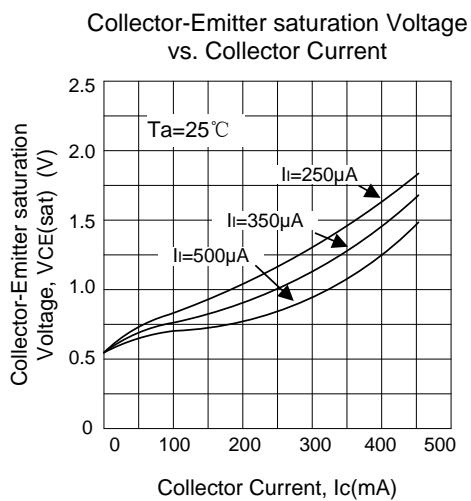
Note: A. The Pulse generator has the following characteristics: PRR=12.5kHz, $Z_o=50\Omega$

B. CL includes probe and jig capacitance.

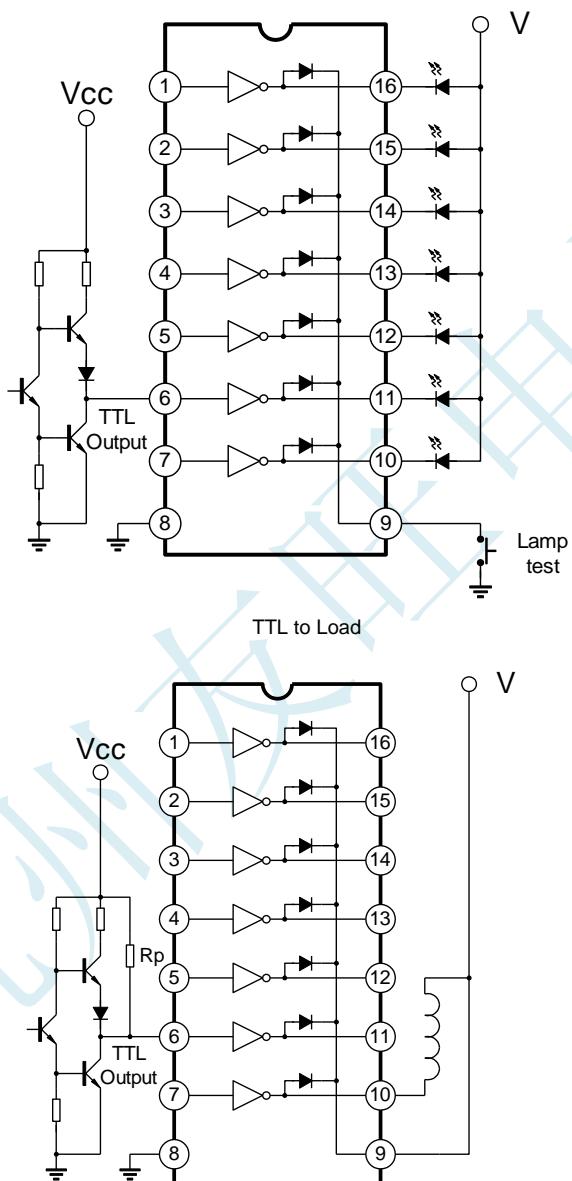
Figure 10. Latch-up Test Circuit and Voltage Waveforms



TYPICAL PERFORMANCE CHARACTERISTICS



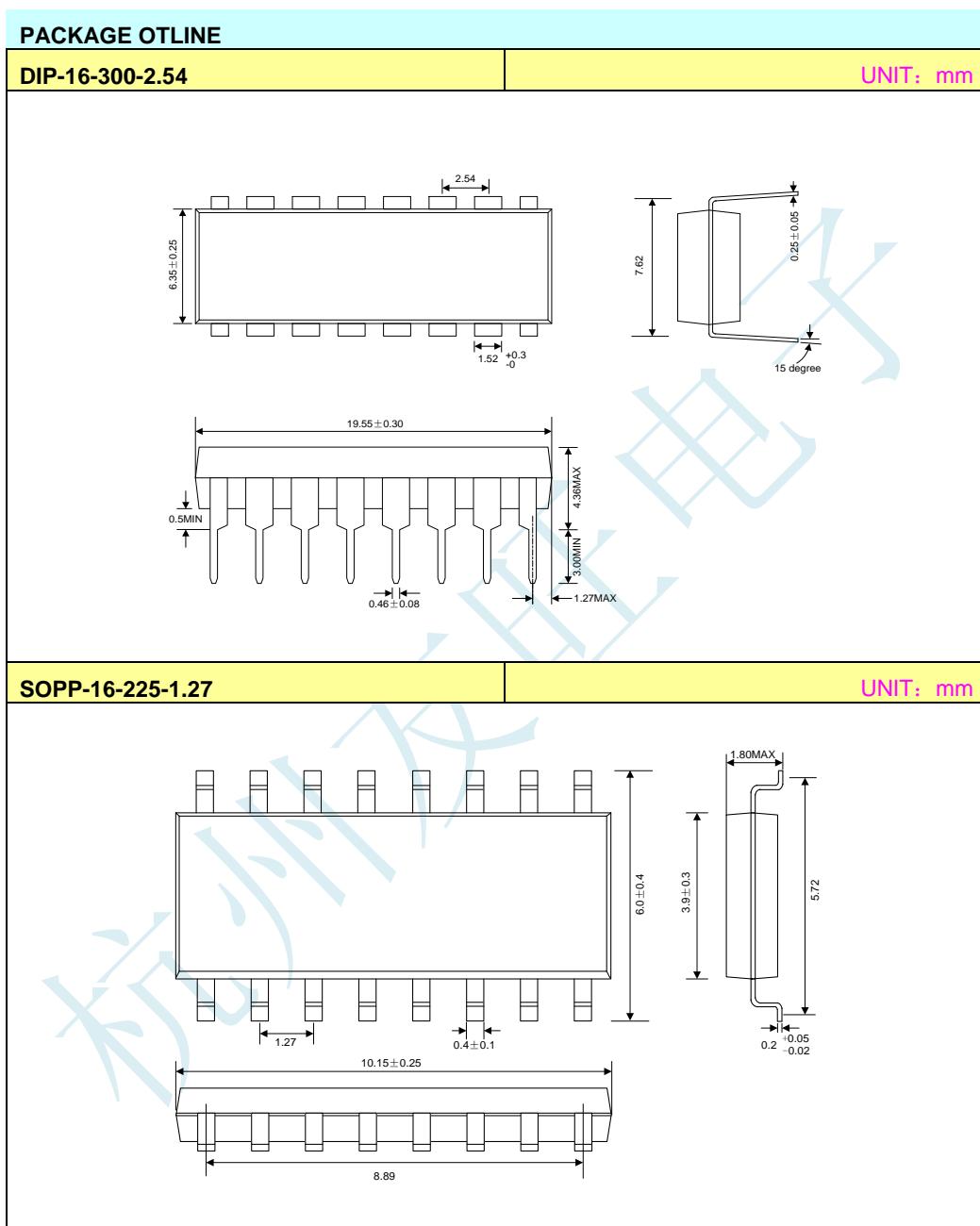
TYPICAL APPLICATION CIRCUIT



Use of pullup Resistor to increase drive Current

ULN2003

LINEAR INTEGRATED CIRCUIT



ELECTROSTATIC DISCHARGE CAUTION

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage handing to prevent electrostatic damage to the device.

NOTICE

HANGZHOU YOUWANG ELECTRONICS CO.LTD assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all HANGZHOU YOUWANG ELECTRONICS CO.LTD's products described or contained herein. HANGZHOU YOUWANG ELECTRONICS CO.LTD's products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.

Attach

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